Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
0.357 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.235 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
Do-13	
Electrode Internally-electrically Connected To Case:	
Cathode	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
13.7 breakdown voltage, dc	
Current Rating Per Characteristic:	
1.00 milliamperes forward current, average peak	
Power Rating Per Characteristic:	
1.0 watts small-signal input power, common-collector major	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., th	nat reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publicatio	ons, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typ	vical", "average", "", etc.).
Terminal Type And Quantity:	
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/500 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	